

## **isc** Silicon NPN Darlington Power Transistor

# 2SD2022

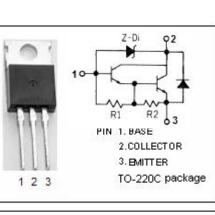
### DESCRIPTION

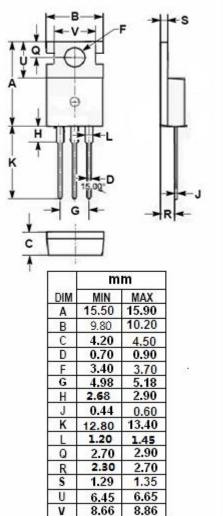
- High DC Current Gain-
- : h<sub>FE</sub> = 3000(Min)@ I<sub>C</sub>= 1A
- Low Collector-Emitter Saturation Voltage-
- : V<sub>CE(sat)</sub> = 1.5V(Max)@ I<sub>C</sub>= 1A
- Incorporating a built-in zener diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

- · Low-frequency amplifications.
- Power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>CBO</sub>	Collector-Base Voltage	50-70	V			
V <sub>CEO</sub>	Collector-Emitter Voltage	50-70	V			
V <sub>EBO</sub>	Emitter-Base Voltage	5	V			
lc	Collector Current-Continuous	2	A			
I <sub>CM</sub>	Base Current-Peak	3	A			
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃	25	W			
TJ	Junction Temperature	150	°C			
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C			





isc website: www.iscsemi.com



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>B</sub> = 0	50		70	V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =0.1mA; I <sub>E</sub> = 0	50		70	V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 3mA; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1Α; I <sub>B</sub> = 1mΑ			1.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1Α; I <sub>B</sub> = 1mA			2.0	V
І <sub>сво</sub>	Collector Cutoff Current	V <sub>CB</sub> = 40V; I <sub>E</sub> = 0			10	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			3.0	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 2V	3000			

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